Plastic Infrared Emitting Diode OP240 Series OP245 Series Features: Wide irradiance pattern Side-looking package for space-limited applications Wavelength matched to silicon's peak response Mechanically and spectrally matched to other OPTEK products

Description:

Each device in this series is a high intensity gallium aluminum arsenide infrared emitting diode that is suited for use as a PCBoard mounted slotted switch or an easy mount PCBoard interrupter.

Each dome lens **OP240** and **OP245** device is an 890 nm diode that is molded in an IR-transmissive clear epoxy side-looking package. *OP240 is mechanically and spectrally matched to the OP550 and OP560 series of phototransistors. OP245 is mechanically and spectrally matched to the OP555 and OP565 series devices.*

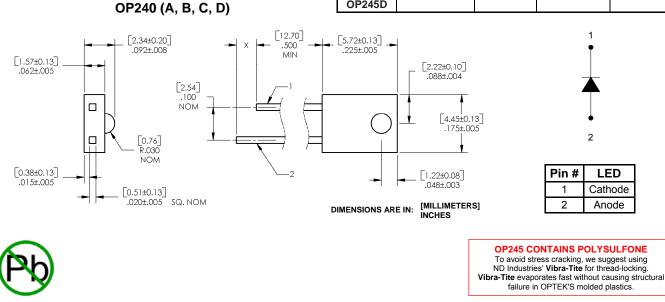
Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- PCBoard mounted slotted switch
- PCBoard interrupter

RoHS

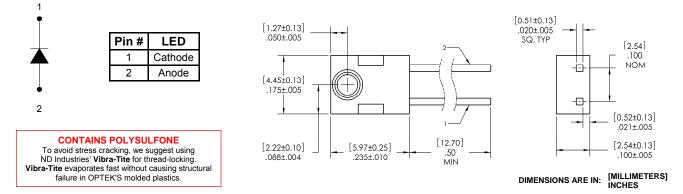
Ordering Information						
Part Number	LED Peak Wavelength	Lens Type	Total Beam Angle	Lead Length		
OP240A						
OP240B		Dome				
OP240C		Dome				
OP240D	890 nm		40°	0.50"		
OP245A	890 mm		40	minimum		
OP245B		Recessed				
OP245C		Recessed				
OP245D						



OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.



OP245 (A, B, C, D)



Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage and Operating Temperature Range	-40° C to +100° C
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current	3.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾
Power Dissipation	100 mW ⁽²⁾

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS

Input Diode

E _{e (APT)}	Apertured Radiant Incidence OP240A, OP245A OP240B, OP245B OP240C, OP245C OP240D, OP245D	0.60 0.40 0.20 0.05	- - -	- 1.20 0.86 -	mW/cm ²	I _F = 20 mA ⁽³⁾	
V_{F}	Forward Voltage	-	-	1.80	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μA	V _R = 2.0 V	
λ_{P}	Wavelength at Peak Emission	-	890	-	nm	I _F = 10 mA	
В	Spectral Bandwidth between Half Power Points	-	80	-	nm	I _F = 10 mA	
$\Delta\lambda_{P}/\DeltaT$	Spectral Shift with Temperature	-	±0.18	-	nm/°C	I _F = Constant	
θ_{HP}	Emission Angle at Half Power Points	-	40	-	Degree	I _F = 20 mA	
tr	Output Rise Time	-	500	-	ns	I _{F(PK)} =100 mA, PW=10 μs, and	
t _f	Output Fall Time	-	250	-	ns	D.C.=10.0%	

Notes:

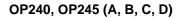
1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.

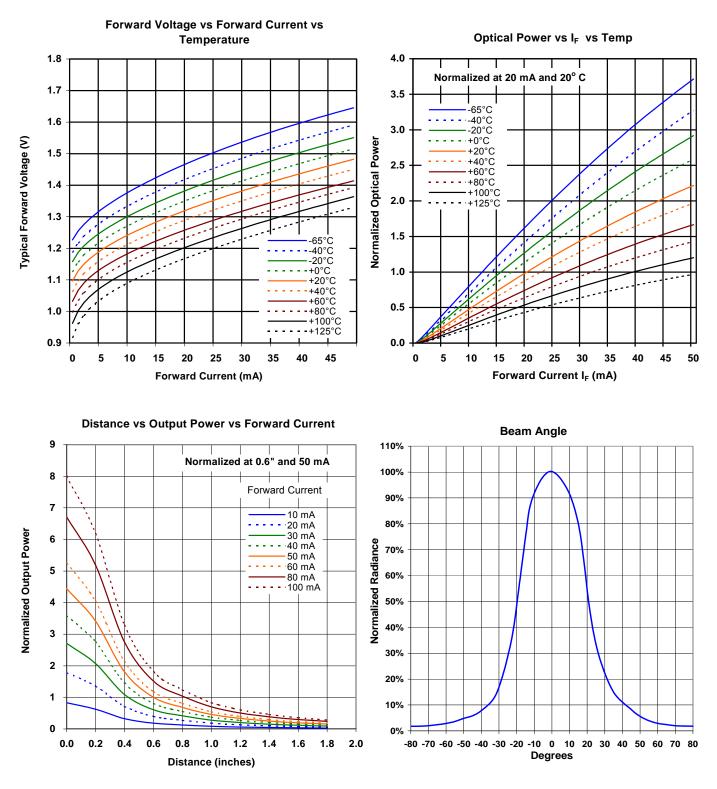
2. Derate linearly 1.33 mW/° C above 25° C.

 E_{E(APT)} is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (6.60 mm) from the lens tip. E_{E(APT)} is not necessarily uniform within the measured area.

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